SPECIFICATION AMENDMENTS

Please amend the specification by replacing the paragraphs below.

[0026] United States Patent Applications, Serial Nos. 10/254483 and 10/254290 filed on

September 24, 2002, published as 2004-0060031-A1 and 2004-0057285-A1, disclose a memory

architecture in which a page of contiguous memory storage units are programmed or read in

parallel. As programming is performed on a page of contiguous memory storage units, during

the process those memory storage units that have been programmed to their targeted state will be

program-inhibited or locked out from further programming. In a preferred scheme, the memory

storage units are locked out by floating their channels and boosting the voltage there to inhibit

programming. This boosted voltage creates a significant perturbation on an adjacent storage unit

still under programming.

[0052] The sense module 380 shown in FIG. 4A, FIG. 4B and FIG. 12 is preferably

implemented in a memory architecture configured to perform all-bit-line sensing. In other

words, contiguous memory cells in a row are each connectable to a sense module to perform

sensing in parallel. Such a memory architecture is also disclosed in co-pending and commonly

assigned United States Patent Application Serial No. 10/254,483 filed by Cernea et al., on

September 24, 2002 entitled, "Highly Compact Non-Volatile Memory And Method Thereof."

Thereof", which published as 2004-0060031-A1. The entire disclosure of said patent application

is hereby incorporated herein by reference.

[0112] FIGs. 8(H)-8(O) illustrates the timing of the preferred sense module shown in FIG. 12

in relation to the features of the present invention. Detailed description of the operation of the

preferred sense module in regards to other inventive features has been described and claimed in

co-pending and co-owned United States Patent Application Serial Number, 10/254830 filed on

September 24, 2002 by Adrian-Raul Cernea and Yan Li, published as 2004-0057287-A1. The

entire disclosure of the referenced application is hereby incorporated herein by reference.

Attorney Docket No.: SNDK.308US0

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Application No.: 10/667,222

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